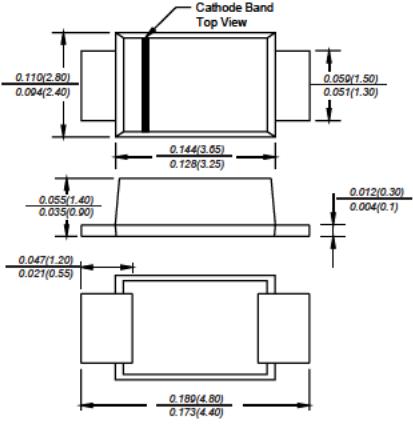


## II. Schottky Rectifier

### 3.0A Surface Mount Schottky Rectifier

S32AF~S320AF

(Package: SMAF)

<p><b>FEATURES</b></p> <ul style="list-style-type: none"> <li>The plastic package carries Underwriters Laboratory Flammability Classification 94V-0</li> <li>For surface mounted applications</li> <li>Metal silicon junction, majority carrier conduction</li> <li>Low power loss, high efficiency</li> <li>Built-in strain relief, ideal for automated placement</li> <li>High forward surge current capability</li> <li>High temperature soldering guaranteed : 260°C/10 seconds at terminals</li> </ul> <p><b>MECHANICAL DATA</b></p> <ul style="list-style-type: none"> <li>Case : SMAF molded plastic body</li> <li>Terminals : Leads solderable per MIL-STD-750, Method 2026</li> <li>Polarity : Color band denotes cathode end</li> <li>Mounting Position : Any</li> <li>Weight : 0.038 grams</li> </ul>	 <p>Cathode Band Top View</p> <p>Dimensions in inches and (millimetres)</p>
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### Ratings & Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristics	Symbol	S32AF	S33AF	S34AF	S35AF	S36AF	S38AF	S310AF	S315AF	S320AF	Units						
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	150	200	Volts						
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	105	140	Volts						
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	150	200	Volts						
Maximum average forward rectified current	I <sub>o</sub>	3.0									Amps						
Non-repetitive peak forward surge current 8.3ms single half sine-wave	I <sub>FSM</sub>	100.0									Amps						
Maximum forward voltage at 3.0A	V <sub>F</sub>	0.55		0.70		0.85		0.95		Volts							
Maximum reverse current Ta = 25°C at V <sub>DC</sub> Ta = 100°C	I <sub>R</sub>	0.5 20.0									mA						
Typical thermal resistance (Note 1)	R <sub>th-JA</sub> R <sub>th-JL</sub>	55.0 17.0									°C/w						
Typical junction capacitance V <sub>R</sub> = 4.0V, F = 1MHz	C <sub>j</sub>	160.0									PF						
Operating junction temperature range	T <sub>j</sub>	-55 to +125				-55 to +150				°C							
Storage temperature range	T <sub>stg</sub>	-55 to +150									°C						

Notes:

1. Thermal resistance from junction to ambient, PCB mounted.

## Ratings and Characteristic Curves of S32AF~S320AF

